## NSN 5961-01-100-5887

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View Online at https://aerobasegroup.com/nsn/5961-01-100-5887 **Inclosure Material:** Metal **Overall Length:** 0.180 inches **Overall Diameter:** 0.280 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 55.0 breakdown voltage, collector-to-base, emitter open and 33.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 13499-352-1059 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a

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**Unit Of Measure:** 

**Demilitarization:** Yes - demil/mli